

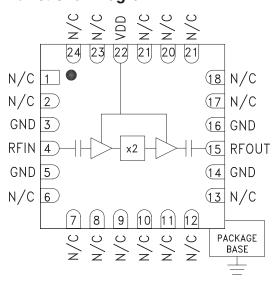


Typical Applications

The HMC577LC4B is suitable for:

- Clock Generation Applications: SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Functional Diagram



Features

Very High Output Power: +20 dBm Low Input Power Drive: -2 to +6 dBm

Very High Fo, 3Fo Isolation: >55 dBc @ Fout= 29 GHz

100 KHz SSB Phase Noise: -128 dBc/Hz

Single Supply: +5V@ 213 mA

RoHS Compliant 4x4 mm SMT Package

General Description

The HMC577LC4B is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a leadless RoHS compliant SMT package. When driven by a +5 dBm signal, the multiplier provides +20 dBm typical output power from 27 to 31 GHz. The Fo and 3Fo isolations are >55 dBc at 29 GHz. The HMC577LC4B is ideal for use in LO multiplier chains for Pt to Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -128 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC577LC4B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

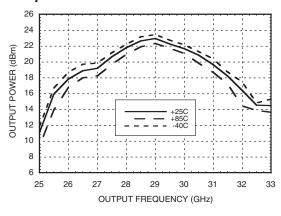
Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd = +5V, 5 dBm Drive Level

| Parameter | Min. | Тур. | Max. | Units |
|--|-------------|------|------|--------|
| Frequency Range, Input | 13.5 - 15.5 | | | GHz |
| Frequency Range, Output | 27 - 31 | | | GHz |
| Output Power | 15 | 20 | | dBm |
| Fo Isolation (with respect to output level) | | 60 | | dBc |
| 3Fo Isolation (with respect to output level) | | 55 | | dBc |
| Input Return Loss | | 20 | | dB |
| Output Return Loss | | 7 | | dB |
| SSB Phase Noise (100 kHz Offset) | | -128 | | dBc/Hz |
| Supply Current (Idd) | | 213 | | mA |

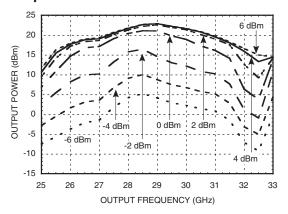




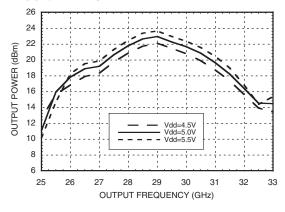
Output Power vs. Temperature @ 5 dBm Drive Level



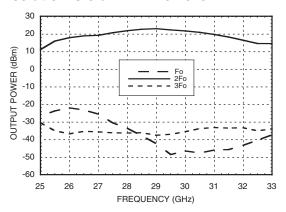
Output Power vs. Drive Level



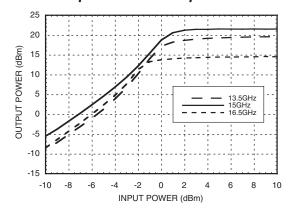
Output Power vs. Supply Voltage @ 5 dBm Drive Level



Isolation @ 5 dBm Drive Level



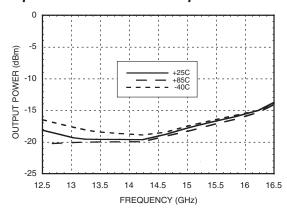
Output Power vs. Input Power



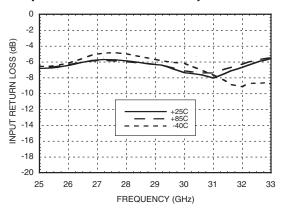




Input Return Loss vs. Temperature



Output Return Loss vs. Temperature







Absolute Maximum Ratings

| RF Input (Vdd = +5V) | +13 dBm |
|--|----------------|
| Supply Voltage (Vdd) | +6.0 V |
| Channel Temperature | 175 °C |
| Continuous Pdiss (T= 85 °C) (derate 13.8 mW/°C above 85 °C) | 1.24 W |
| Thermal Resistance (channel to ground paddle) | 73 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |

Typical Supply Current vs. Vdd

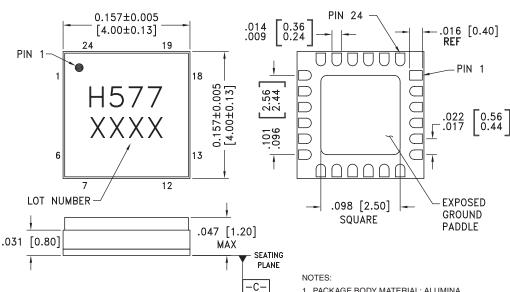
| Vdd (Vdc) | Idd (mA) |
|-----------|----------|
| 4.5 | 212 |
| 5.0 | 213 |
| 5.5 | 214 |

Multiplier will operate over full voltage range shown above.



Outline Drawing

BOTTOM VIEW



- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.





Pin Description

| Pin Number | Function | Description | Interface Schematic | | |
|------------------------------|----------|---|---------------------|--|--|
| 1, 2, 6-13, 17-21, 23, 24 | N/C | These pins are internally not connected; however, this product was specified with these pins connected to RF/DC ground. | | | |
| 3, 5, 14, 15 | GND | Package bottom must also be connected to RF/DC ground. | GND = | | |
| 4 | RFIN | Pin is AC coupled and matched to 50 Ohms from 13.5 - 15.5 GHz. | RFIN ○── ├── | | |
| 15 | RFOUT | Pin is AC coupled and matched to 50 Ohms from 27 - 31 GHz. | — —o rfout | | |
| 22 | Vdd | Supply voltage 5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required. | oVdd — — — | | |

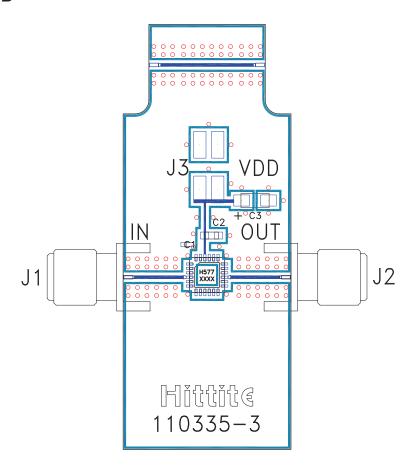
Application Circuit

| Component | Value | | | Ç |) J3 | | | |
|-----------|----------|---|------|----------|-------|------|---------|---------------|
| C1 | 100 pF | | | - | | | | |
| C2 | 1,000 pF | | | | C1 = | = C2 | <u></u> | C3 <u></u> |
| C3 | 2.2 μF | | | | | = | \perp | |
| | | | | | _ | _ | _ | _ |
| | | | | | 22 | | | |
| | | | | Vo | dd | | | |
| | | | | | | | | |
| | | | | | | | | |
| | | 4 | | | | | 15 | |
| | <u> </u> | | RFIN | | RF | OUT | | $\overline{}$ |
| | J1 | | Н | MC57 | 7LC4E | 3 | | J2 |
| | | | | G١ | 1D | | | |
| | | | | | 3,5,1 | 4,16 | | |
| | | | | <u> </u> | | | | |





Evaluation PCB



List of Materials for Evaluation PCB 115223 [1]

| Item | Description | | | |
|---------|---------------------------------|--|--|--|
| J1, J2 | PCB Mount SRI K Connector | | | |
| J3 | Molex Header, 2mm | | | |
| C1 | 100 pF Capacitor, 0402 Pkg. | | | |
| C2 | 1,000 pF Capacitor, 0603 Pkg. | | | |
| C3 | 2.2 µF Tantalum Capacitor | | | |
| U1 | HMC577LC4B x2 Active Multiplier | | | |
| PCB [2] | 110335 Eval Board | | | |

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350